NSN 5961-01-088-5464

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-088-5464 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.202 inches and 0.224 inches **Terminal Length:** Between 0.060 inches and 0.064 inches **Overall Diameter:** Between 0.118 inches and 0.123 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector of standard range **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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